

C3D06060G–Silicon Carbide Schottky Diode

Z-REC™ RECTIFIER

$V_{RRM} = 600\text{ V}$
 $I_F = 6\text{ A}$
 $(T_C < 155^\circ\text{C})$
 $Q_c = 16\text{ nC}$

Features

- 600-Volt Schottky Rectifier
- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- High-Frequency Operation
- Temperature-Independent Switching Behavior
- Extremely Fast Switching
- Positive Temperature Coefficient on V_F

Benefits

- Replace Bipolar with Unipolar Rectifiers
- Essentially No Switching Losses
- Higher Efficiency
- Reduction of Heat Sink Requirements
- Parallel Devices Without Thermal Runaway

Applications

- Switch Mode Power Supplies
- Power Factor Correction
 - Typical PFC P_{out} : 600W-1200W
- Motor Drives
 - Typical Power : 2HP-3HP

Package



TO-263-2



Part Number	Package	Marking
C3D06060G	TO-263-2	C3D06060

Maximum Ratings

Symbol	Parameter	Value	Unit	Test Conditions	Note
V_{RRM}	Repetitive Peak Reverse Voltage	600	V		
V_{RSM}	Surge Peak Reverse Voltage	600	V		
V_{DC}	DC Blocking Voltage	600	V		
I_F	Continuous Forward Current	6 8	A	$T_C < 155^\circ\text{C}$ $T_C < 145^\circ\text{C}$	See Fig. 3
I_{FRM}	Repetitive Peak Forward Surge Current	41 27	A	$T_C = 25^\circ\text{C}$, $t_p = 10\text{ ms}$, Half Sine Wave, $D=0.3$ $T_C = 110^\circ\text{C}$, $t_p = 10\text{ ms}$, Half Sine Wave, $D=0.3$	
I_{FSM}	Non-Repetitive Peak Forward Surge Current	70 55	A	$T_C = 25^\circ\text{C}$, $t_p = 10\text{ mS}$, Half Sine Wave, $D=0.3$ $T_C = 110^\circ\text{C}$, $t_p = 10\text{ mS}$, Half Sine Wave, $D=0.3$	
I_{FSM}	Non-Repetitive Peak Forward Surge Current	200	A	$T_C = 25^\circ\text{C}$, $t_p = 10\text{ }\mu\text{s}$, Pulse	
P_{tot}	Power Dissipation	91 39	W	$T_C = 25^\circ\text{C}$ $T_C = 110^\circ\text{C}$	
T_J, T_{stg}	Operating Junction and Storage Temperature	-55 to +175	$^\circ\text{C}$		
	TO-220 Mounting Torque	1 8.8	Nm lbf-in	M3 Screw 6-32 Screw	

Electrical Characteristics

Symbol	Parameter	Typ.	Max.	Unit	Test Conditions	Note
V_F	Forward Voltage	1.6 1.9	1.8 2.4	V	$I_F = 6\text{ A}$ $T_J = 25^\circ\text{C}$ $I_F = 6\text{ A}$ $T_J = 175^\circ\text{C}$	
I_R	Reverse Current	10 20	50 200	μA	$V_R = 600\text{ V}$ $T_J = 25^\circ\text{C}$ $V_R = 600\text{ V}$ $T_J = 175^\circ\text{C}$	
Q_C	Total Capacitive Charge	16		nC	$V_R = 600\text{ V}$, $I_F = 6\text{ A}$ $di/dt = 500\text{ A}/\mu\text{s}$ $T_J = 25^\circ\text{C}$	
C	Total Capacitance	294 27 26		pF	$V_R = 0\text{ V}$, $T_J = 25^\circ\text{C}$, $f = 1\text{ MHz}$ $V_R = 200\text{ V}$, $T_J = 25^\circ\text{C}$, $f = 1\text{ MHz}$ $V_R = 400\text{ V}$, $T_J = 25^\circ\text{C}$, $f = 1\text{ MHz}$	

Note:

1. This is a majority carrier diode, so there is no reverse recovery charge.

Thermal Characteristics

Symbol	Parameter	Typ.	Unit
$R_{\theta JC}$	Thermal Resistance from Junction to Case	1.65	$^\circ\text{C}/\text{W}$

Typical Performance

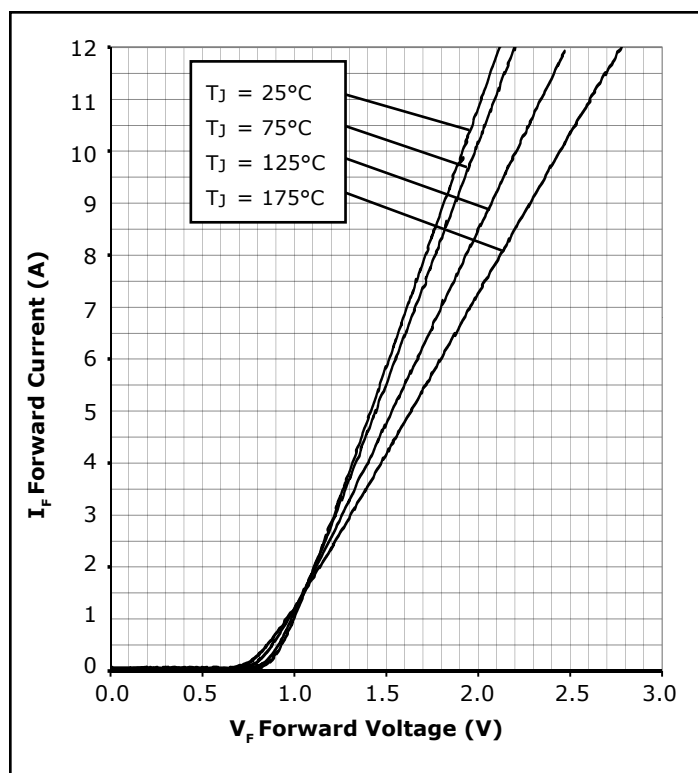


Figure 1. Forward Characteristics

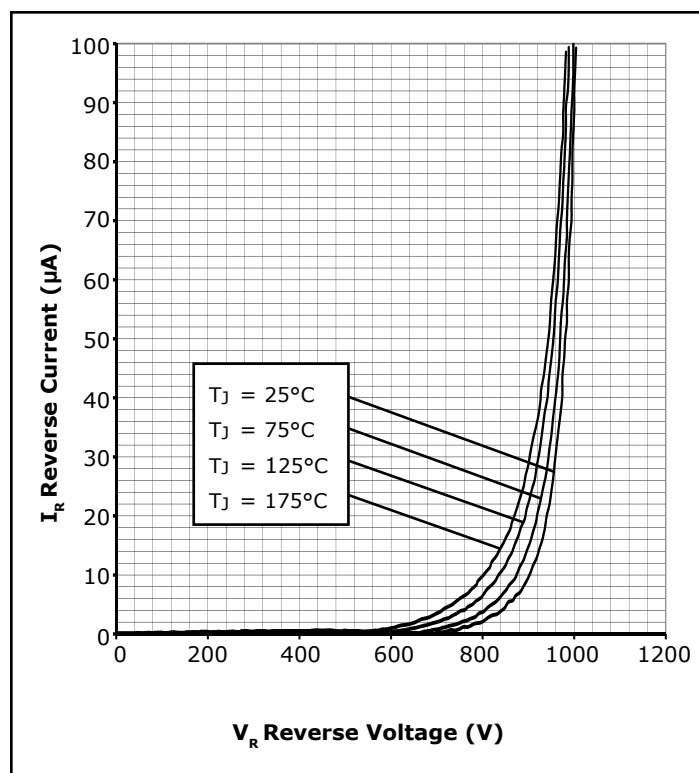


Figure 2. Reverse Characteristics

Typical Performance

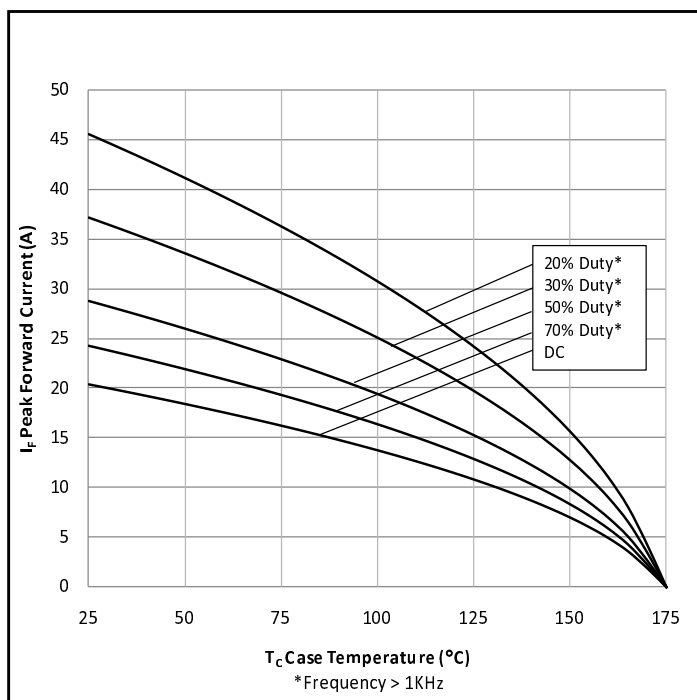


Figure 3. Current Derating

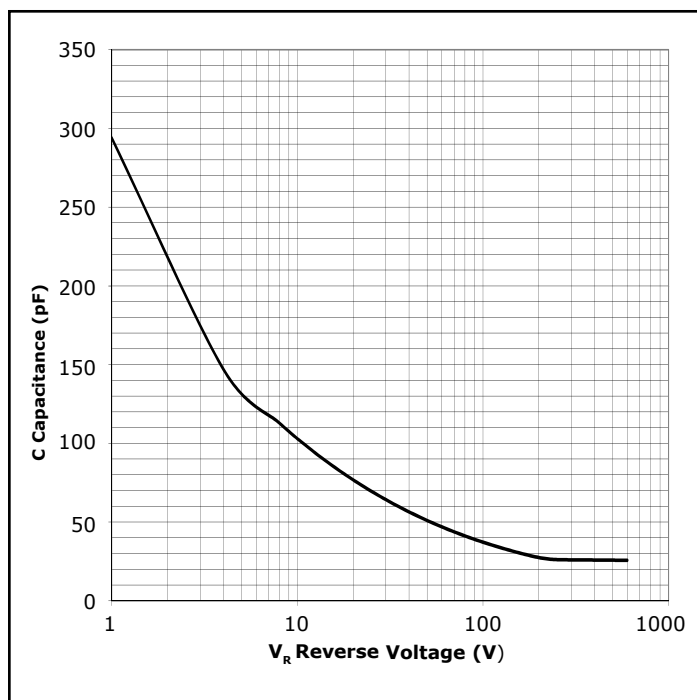


Figure 4. Capacitance vs. Reverse Voltage

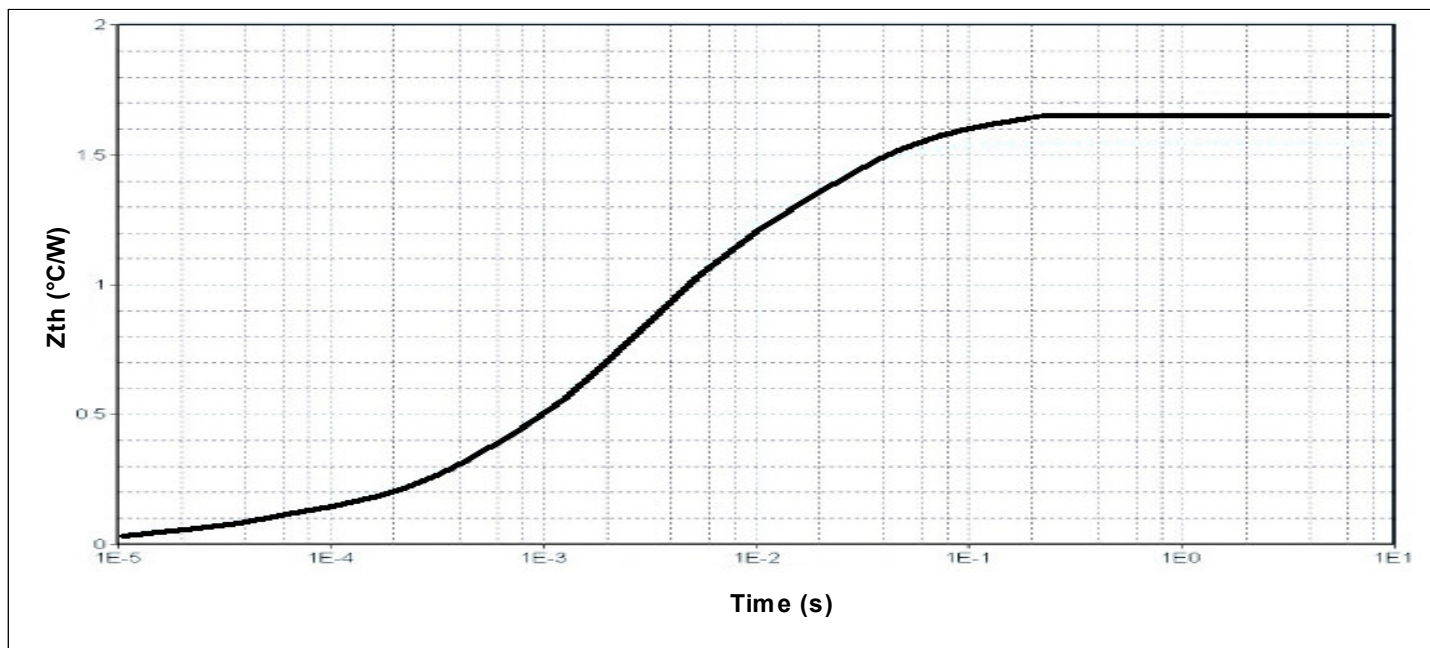


Figure 5. Transient Thermal Impedance

Typical Performance

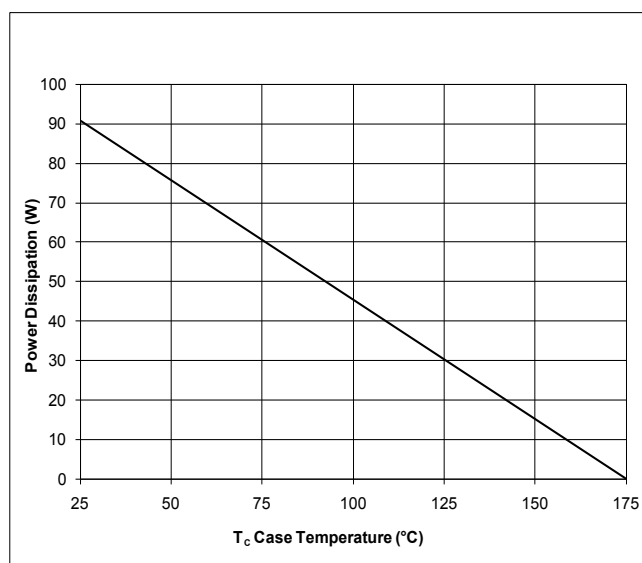
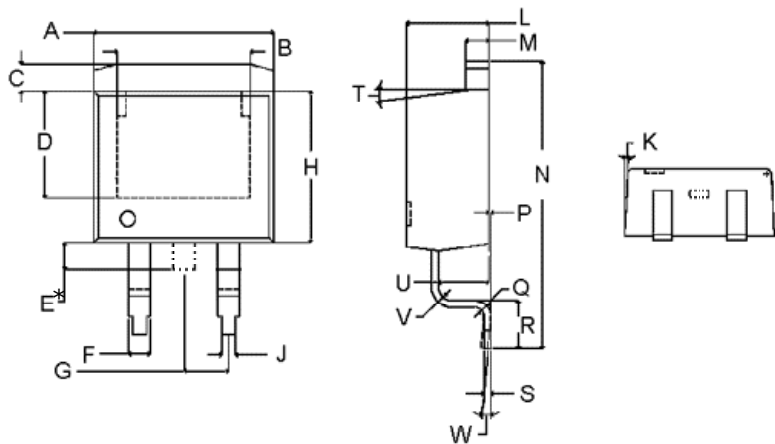


Figure 6. Power Derating



Package Dimensions

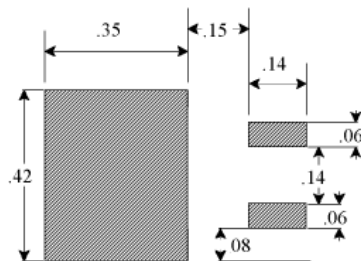
Package TO-263-2



POS	Inches		Millimeters	
	Min	Max	Min	Max
A	.396	.406	10.058	10.312
B	.295	.335	7.493	8.509
C	.05	.065	1.27	1.651
D	.25	.27	6.35	6.858
E*	0.00	.07	0.00	1.778
F	.048	.062	1.219	1.575
G	.100 TYP		2.540 TYP	
H	.35	.37	8.890	9.398
J	.028	.034	.711	.864
K	2°	5°	2°	5°
L	.170	.180	4.318	4.572
M	.045	.055	1.143	1.397
N	.595	.615	15.113	15.621
P	0.00	0.10	0.00	2.54
Q	R0.018 TYP	R0.022 TYP	R0.457 TYP	R0.559 TYP
R	.090	.110	2.286	2.794
S	.013	.02	.330	.508
T	6.5°	8.5°	6.5°	8.5°
U	.100	.107	2.540	2.718
W	—	5.0°	—	5.0°

Note:
* Tab "E" may not be present

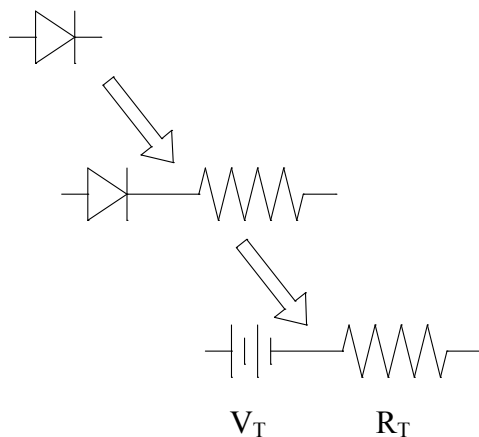
Recommended Solder Pad Layout



TO-263-2

Part Number	Package	Marking
C3D06060G	TO-263-2	C3D06060

Diode Model



$$V_{fT} = V_T + I_f \cdot R_T$$

$$V_T = 0.975 + (T_j \cdot -1.0 \cdot 10^{-3})$$

$$R_T = 0.09 + (T_j \cdot 0.51 \cdot 10^{-3})$$

Note: T_j = Diode Junction Temperature In Degrees Celcius

"The levels of environmentally sensitive, persistent biologically toxic (PBT), persistent organic pollutants (POP), or otherwise restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2002/95/EC on the restriction of the use of certain hazardous substances in electrical and electronic equipment (RoHS), as amended through April 21, 2006.

This product has not been designed or tested for use in, and is not intended for use in, applications implanted into the human body nor in applications in which failure of the product could lead to death, personal injury or property damage, including but not limited to equipment used in the operation of nuclear facilities, life-support machines, cardiac defibrillators or similar emergency medical equipment, aircraft navigation or communication or control systems, air traffic control systems, or weapons systems.

Copyright © 2006-2009 Cree, Inc. All rights reserved. The information in this document is subject to change without notice. Cree and the Cree logo are registered trademarks and Z-Rec is a trademark of Cree, Inc.

Cree, Inc.
4600 Silicon Drive
Durham, NC 27703
USA Tel: +1.919.313.5300
Fax: +1.919.313.5451
www.cree.com/power

Компания «Life Electronics» занимается поставками электронных компонентов импортного и отечественного производства от производителей и со складов крупных дистрибьюторов Европы, Америки и Азии.

С конца 2013 года компания активно расширяет линейку поставок компонентов по направлению коаксиальный кабель, кварцевые генераторы и конденсаторы (керамические, пленочные, электролитические), за счёт заключения дистрибьюторских договоров

Мы предлагаем:

- Конкурентоспособные цены и скидки постоянным клиентам.
- Специальные условия для постоянных клиентов.
- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
- Доставку товара в любую точку России и стран СНГ.
- Комплексную поставку.
- Работу по проектам и поставку образцов.
- Формирование склада под заказчика.
- Сертификаты соответствия на поставляемую продукцию (по желанию клиента).
- Тестирование поставляемой продукции.
- Поставку компонентов, требующих военную и космическую приемку.
- Входной контроль качества.
- Наличие сертификата ISO.

В составе нашей компании организован Конструкторский отдел, призванный помогать разработчикам, и инженерам.

Конструкторский отдел помогает осуществить:

- Регистрацию проекта у производителя компонентов.
- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



Тел: +7 (812) 336 43 04 (многоканальный)

Email: org@lifeelectronics.ru

www.lifeelectronics.ru